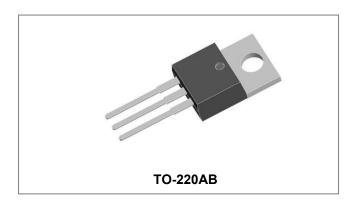


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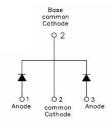
SDUR1060CT ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	5(Per Leg) 10(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	60	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V_{F1}	@ 5A, Pulse, T _J = 25°C	1.14	1.55	V
	V_{F2}	@ 5A, Pulse, T _J = 125°C	0.95	1.45	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25°C	0.007	5	μA
	I _{R2}	@V _R = rated V _R , T _J = 125°C	3	500	μA
Reverse Recovery Time(Per Leg)	t _{rr}	I _F =500mA, I _R =1A,and I _m =250mA	42	50	ns

^{*} Pulse width < 300 μs, duty cycle < 2%



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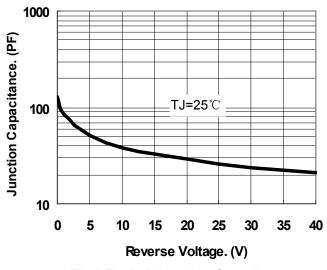




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ Jc	DC operation	4.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

Ratings and Characteristics Curves



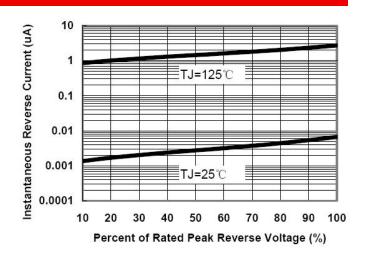


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

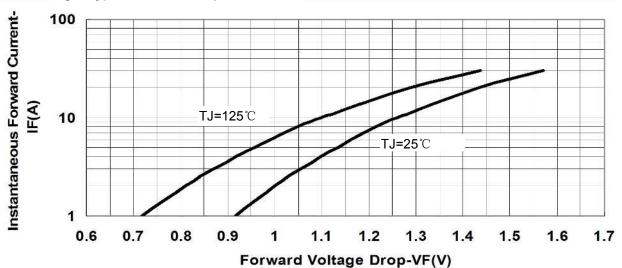


Fig.3-Typical Forward Voltage Drop Characteristics

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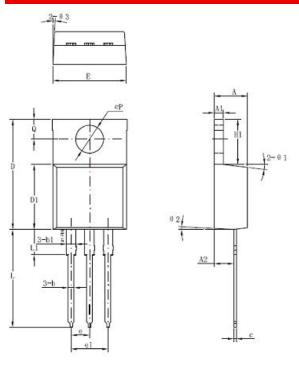


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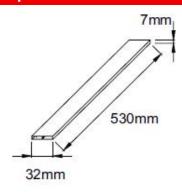


Mechanical Dimensions TO-220AB

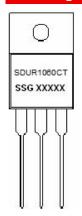


Symbol	Dimensions in millimeters		
	Min	Typical	Max
Α	4.42	4.57	4.72
A1	1.17	1.27	1.37
A2	2.52	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
С	0.31	0.38	0.61
D	14.94	15.24	15.54
D1	8.85	9.00	9.15
E	10.01	10.16	10.31
е		2.54	
e1	4.98	5.06	5.18
H1	6.04	6.24	6.44
L	12.7	13.56	13.80
L1	3.56	3.5	3.96
ФР	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		7°	
Θ2		3°	
Θ3		4°	

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type 10 = Forward Current (10A) 60 = Reverse Voltage(600V) CT = Configuration

 $\begin{array}{ll} \text{CT} & = \text{Configuration} \\ \text{SSG} & = \text{SSG} \\ \text{YY} & = \text{Year} \\ \text{WW} & = \text{Week} \\ \text{L} & = \text{Lot Number} \end{array}$

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
SDUR1060CT	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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SDUR1060CT



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